

L Number	Hits	Search Text	DB	Time stamp
37	160	cumulative near6 capacitance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:13
38	115391	storage near6 (capacity or capacitor or capacitance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:18
39	3362	second near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:18
40	1703	storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:19
41	84809	gate near6 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:21
42	1	(cumulative near6 capacitance) and (second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line) and (gate near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:22
43	425	(second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line) and (gate near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:23
44	1	(cumulative near6 capacitance) and ((second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line) and (gate near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:23
45	25	(second near6 pixel near6 electrode) near6 (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line) near6 (gate near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:29
46	13600	holding near6 period	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:30
47	10	((second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line) and (gate near6 line)) and (holding near6 period)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:33
50	0	(cumulative near6 capacitance) near6 between near6 (second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:38

51	0	(cumulative near6 capacitance) near6 between near6 ((second near6 pixel near6 electrode) and (storage near6 (capacity or capacitor or capacitance) near6 electrode near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:40
52	0	(cumulative near6 capacitance) near6 between near6 ((second near6 pixel near6 electrode) and (gate near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:41
-	3549	first near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:44
-	3362	second near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:44
-	3549	first near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:45
-	10492	first near6 electric near6 field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:46
-	9405	second near6 electric near6 field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:47
-	63	(first near6 pixel near6 electrode) near6 (first near6 electric near6 field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:47
-	54	(second near6 pixel near6 electrode) near6 (second near6 electric near6 field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:47
-	28	((first near6 pixel near6 electrode) near6 (first near6 electric near6 field)) and ((second near6 pixel near6 electrode) near6 (second near6 electric near6 field))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:52
-	1	"10/057952"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 10:49
-	5	((first near6 pixel near6 electrode) near6 (first near6 electric near6 field)) and ((second near6 pixel near6 electrode) near6 (second near6 electric near6 field)) and strength	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:05
-	468166	insulat\$3 near6 (film or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:07

-	1640	(first near6 pixel near6 electrode) and (second near6 pixel near6 electrode) and (insulat\$3 near6 (film or layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:07
-	947	349\$.ccls. and ((first near6 pixel near6 electrode) and (second near6 pixel near6 electrode) and (insulat\$3 near6 (film or layer)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:08
-	6153	(first near6 electric near6 field) and (second near6 electric near6 field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:09
-	122	(349\$.ccls. and ((first near6 pixel near6 electrode) and (second near6 pixel near6 electrode) and (insulat\$3 near6 (film or layer)))) and ((first near6 electric near6 field) and (second near6 electric near6 field))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:10
-	22	((349\$.ccls. and ((first near6 pixel near6 electrode) and (second near6 pixel near6 electrode) and (insulat\$3 near6 (film or layer)))) and ((first near6 electric near6 field) and (second near6 electric near6 field))) and @py<2001	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:42
-	30893	different near6 voltages	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:45
-	17	spatially near6 (different near6 voltages)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:45
-	661	349\$.ccls. and (different near6 voltages)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:48
-	21	compensator and (349\$.ccls. and (different near6 voltages))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 13:12
-	38	349/117\$.ccls. and (different near6 voltages)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 11:49

L Number	Hits	Search Text	DB	Time stamp
1	3549	first near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:17
2	3362	second near6 pixel near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:17
3	354	(first near6 pixel near6 electrode) near6 connect\$6 near6 (second near6 pixel near6 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:18
4	353	(first near6 pixel near6 electrode) near6 connect\$3 near6 (second near6 pixel near6 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:19
5	468166	insulat\$3 near6 (film or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:20
6	46	((first near6 pixel near6 electrode) near6 connect\$3 near6 (second near6 pixel near6 electrode)) near6 (insulat\$3 near6 (film or layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:20
7	22	((((first near6 pixel near6 electrode) near6 connect\$3 near6 (second near6 pixel near6 electrode)) near6 (insulat\$3 near6 (film or layer))) and @py<2001	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/16 14:21